

PJSD07LCFN2

Transient Voltage Suppressors for ESD Protection General Description

The PJSD07LCFN2 is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.

Applications

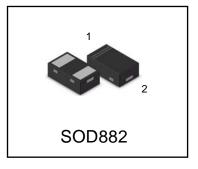
- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

Features

- Small Body Outline Dimensions
- Low Body Height
- Peak Power up to 150 Watts @ 8 x 20 μs
 Pulse
- Low Leakage current
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

Absolute Ratings (T_{amb}=25°C)

Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power ($t_p = 8/20 \ \mu \ s$)	150	W
TL	Maximum lead temperature for soldering during 10s	260	°C
T _{stg}	Storage Temperature Range	-55 to +155	°C
T _{op}	Operating Temperature Range	-40 to +125	°C
Tj	Maximum junction temperature	150	°C
	IEC61000-4-2 (ESD) air discharge contact discharge	土15 土8	KV
	IEC61000-4-4 (EFT)	40	А
	ESD Voltage Per Human Body Model	16	KV



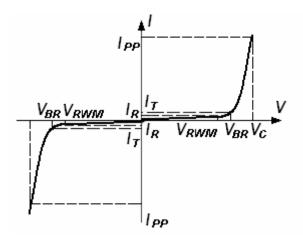




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Electrical Parameter

Symbol	Parameter						
I _{PP}	Maximum Reverse Peak Pulse Current						
Vc	Clamping Voltage @ IPP						
V _{RWM}	Working Peak Reverse Voltage						
I _R	Maximum Reverse Leakage Current @ V _{RWM}						
Ι _τ	Test Current						
V _{BR}	Breakdown Voltage @ I_T						



Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.VF = 0.9V at IF = 10	0mA
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Device	V _{RWM} (V)	I _{R1} (uA) @ V _{RWM}	I _{R2} (uA) @V _R =3.5∨	V _{BR} (V)@ I _T (Note 1)	Ι _τ	V _c (V) @ I _{PP} =5 A*	V _C (V) @ Max I _{PP} *	І _{РР} (А)*	Р _{РК} (W)*	C (pF)
	Max	Max	Мах	Min	mA	Тур	Мах	Max	Max	Тур
PJSD07LCFN2	5.0	0.5	0.3	5.6	1.0	11.6	18.6	9.4	174	15

*Surge current waveform per Figure 1.

1. V_{BR} is measured with a pulse test current I_T at an ambient temperature of $25\,^\circ\!\!\mathbb{C}$.

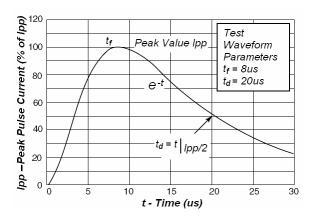


Fig1. Pulse Waveform

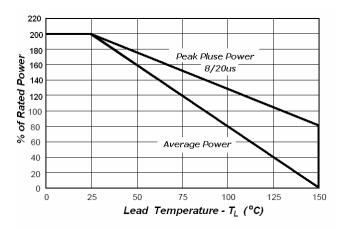


Fig2.Power Derating Curve



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SOD882

DIMENSION OUTLINE:

Unit:mm

